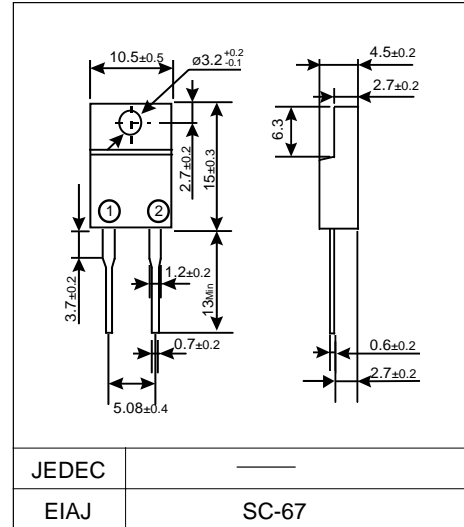


YG811S04R (5A)

(40V / 5A)

SCHOTTKY BARRIER DIODE

Outline drawings, mm



Features

- Insulated package by fully molding
- Low V_f
- Super high speed switching
- High reliability by planer design

Applications

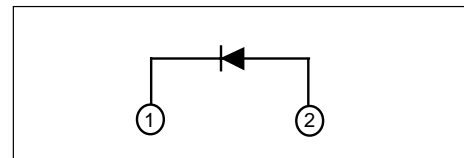
- High speed power switching

Maximum ratings and characteristics

- Absolute maximum ratings

Item	Symbol	Conditions	Rating	Unit
Repetitive peak reverse voltage	V_{RRM}		40	V
Non-repetitive peak reverse voltage	V_{RSM}	$t_w=500\text{ns}$, $\text{duty}=1/40$	48	V
Isolating voltage	V_{ISO}	Terminals to Case, AC. 1min.	1500	V
Average output current	I_o	Square wave, $\text{duty}=1/2$ $T_c=122^\circ\text{C}$	5	A
Surge current	I_{FSM}	Sine wave 10ms	120	A
Operating junction temperature	T_j		-40 to +150	$^\circ\text{C}$
Storage temperature	T_{stg}		-40 to +150	$^\circ\text{C}$

Connection diagram



- Electrical characteristics ($T_a=25^\circ\text{C}$ Unless otherwise specified)

Item	Symbol	Conditions	Max.	Unit
Forward voltage drop	V_{FM}	$I_{FM}=5.0\text{A}$	0.55	V
Reverse current	I_{RRM}	$V_R=V_{RRM}$	5.0	mA
Thermal resistance	$R_{th(j-c)}$	Junction to case	5.0	$^\circ\text{C/W}$

- Mechanical Characteristics

Mounting torque	Recommended torque	0.3 to 0.5	N·m
Weight		2.3	g

Characteristics

